

GT15J331

High Power Switching Applications

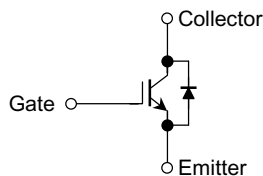
Motor Control Applications

- The 4th Generation
- Enhancement-Mode
- High Speed: $t_f = 0.10 \mu s$ (typ.)
- Low Saturation Voltage: $V_{CE(sat)} = 1.75 V$ (typ.)
- FRD included between Emitter and collector.

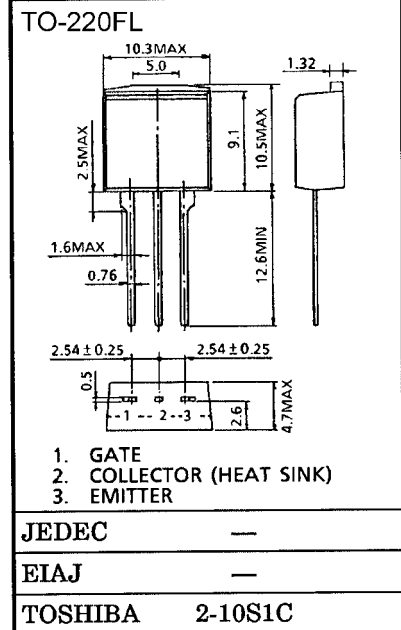
Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-emitter voltage	V_{CES}	600	V
Gate-emitter voltage	V_{GES}	± 20	V
Collector current	DC	I_C	15
	1 ms	I_{CP}	30
Emitter-collector forward current	DC	I_F	15
	1 ms	I_{FM}	30
Collector power dissipation (Tc = 25°C)	P_C	70	W
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	-55~150	°C

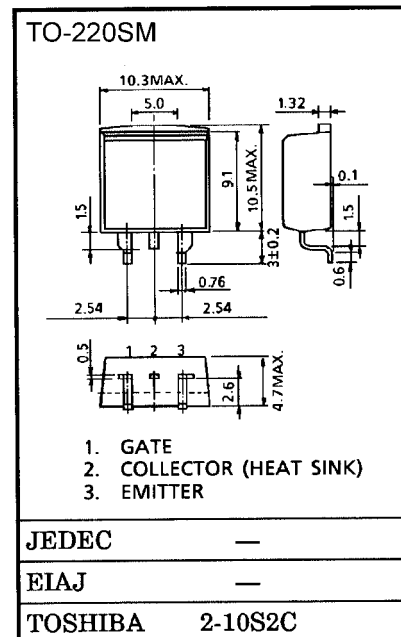
Equivalent Circuit



Unit in mm



Weight : 1.5g



Weight : 1.4g

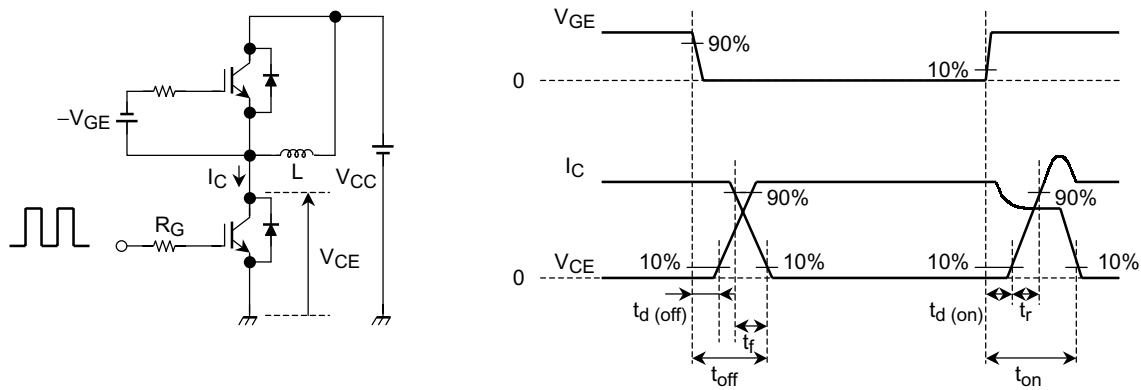
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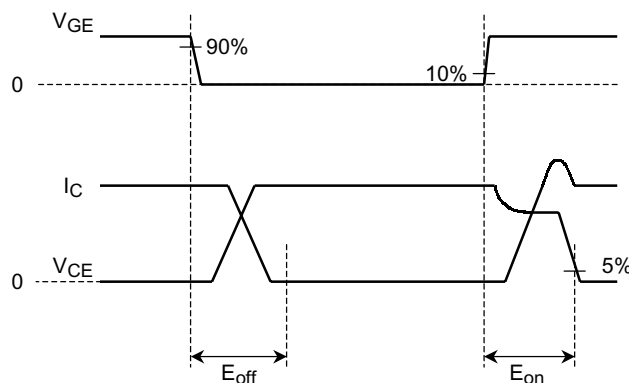
Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GES}	$V_{GE} = \pm 20 \text{ V}, V_{CE} = 0$	—	—	± 500	nA
Collector cut-off current		I_{CES}	$V_{CE} = 600 \text{ V}, V_{GE} = 0$	—	—	1.0	mA
Gate-emitter cut-off voltage		$V_{GE} \text{ (OFF)}$	$I_C = 1.5 \text{ mA}, V_{CE} = 5 \text{ V}$	4.5	—	7.5	V
Collector-emitter saturation voltage		$V_{CE} \text{ (sat)}$	$I_C = 15 \text{ A}, V_{GE} = 15 \text{ V}$	—	1.75	2.3	V
Input capacitance		C_{ies}	$V_{CE} = 20 \text{ V}, V_{GE} = 0, f = 1 \text{ MHz}$	—	2400	—	pF
Switching time	Rise time	t_r	Inductive Load $V_{CC} = 300 \text{ V}, I_C = 15 \text{ A}$ $V_{GG} = 15 \text{ V}, R_G = 43 \Omega$ (Note1)	—	0.04	—	μs
	Turn-on time	t_{on}		—	0.22	—	
	Fall time	t_f		—	0.10	0.23	
	Turn-off time	t_{off}		—	0.37	—	
Peak forward voltage		V_F	$I_F = 15 \text{ A}, V_{GE} = 0$	—	—	2.0	V
Reverse recovery time		t_{rr}	$I_F = 15 \text{ A}, di/dt = -100 \text{ A}/\mu\text{s}$	—	—	200	ns
Thermal resistance (IGBT)		$R_{th} \text{ (j-c)}$	—	—	—	1.79	$^{\circ}\text{C}/\text{W}$
Thermal resistance (Diode)		$R_{th} \text{ (j-c)}$	—	—	—	3.45	$^{\circ}\text{C}/\text{W}$

Note1: Switching time measurement circuit and input/output waveforms



Note2: Switching loss measurement waveforms



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